PCN Number:			20140117001			PCN Date:		01/28/2014			
Title: TLC6C598QDF				leadframe - CN	IS C1309141	L					
Customer Contact:		PCN_ww_ac	lmin_	team@list.ti.con	Phone:	+1(214	1)48(0-6037	Dept	t:	Quality Services
Proposed 1 st Ship Da			te:	07/28/2014	Estimated Sample Availability: Upor			on request			
Change Type:											
Assembly Site				Assembly F	Assembly Process			Assembly Materials			
Design				Electrical S	Electrical Specification			Mechanical Specification			
Test Site				Packing/Sh	Packing/Shipping/Labeling			Test Process			
Wafer Bump Site				Wafer Bum	Wafer Bump Material			Wafer Bump Process			
Wafer Fab Site				Wafer Fab	Wafer Fab Materials			Wafer Fab Process			
				Part numbe	er change						
PCN Details											

Description of Change:

Change the internal leadframe configuration.

Reason for Change:

The current leadframe configuration allows internal bond wire spacing less than 1 wire diameter. Extracts from the current and proposed bond diagrams are shown below. Please note the improved spacing of the red bond wires in the proposed view. Current:





Qualification Data:

Automotive New Product Qualification Plan/Summary (As per AEC-Q100 and JEDEC Guidelines)

Supplier Name:	Texas Instruments Inc.	Supplier Wafer Fabrication Site:	TI Dallas - DMOS5
Supplier Code:		Supplier Die Rev.	В
Supplier Part Number:	TLC6C598QDRQ1	Supplier Assembly/Test Site:	TI Malaysia
Customer Name:		Supplier Package/Pin:	D/16
Customer Part Number:		Pb-Free Lead Frame (Y/N):	Y
Device Description:		"Green" Mold Compound (Y/N):	Y
MSL Rating:	Level3-260C	Operating Temp Range:	-40 to +125C
Peak Solder Reflow Temp:	260C	Automotive Grade Level (1):	1
Prepared by:	Larry Ting	Date:	01/16/2014
Supplier Name:	Texas Instruments Inc.	Supplier Wafer Fabrication Site:	TI Dallas - DMOS5

Test	#	Reference	Test Conditions	Min Lots (2)	SS / lot (2)	Min Total (2)	Results Lot/pass /fail	Comments: (N/A =Not Applicable)	Exceptions to AEC - Q100	
			TEST GROUP A – ACCELERATED ENV	IRONMENT	STRESS T	ESTS (3)				
PC	A1	JESD22-113 J-STD-020	Preconditioning: SMD only; Moisture Preconditioning for THB/HAST, AC/UHST, TC, HTSL, and HTOL	Performed on <u>ALL</u> SMD devices prior to THB/HAST, AC/UHST, TC and PTC						
THB or HAST	A2	JESD22-A101 JESD22-A110	Temperature Humidity Bias: 85°C/85%/1000 hours Highly Accelerated Stress Test: 130°C/85%/96 hours or 110°C/85%/264 hours	3	77	231	Pass	Pass QBS to current leadframe		
AC or UHST	A3	JESD22-A102 JESD22-A118	Autoclave: 121°C/15 psig/96 hours Unbiased Highly Accelerated Stress Test: 130°C/85%/96 hours or 110°C/85%/264 hours	3	77	231	Pass	QBS to current leadframe		
тс	A4	JESD22-A104	Temperature Cycle: -65°C/+150°C/500 cycles	3	77	231	Pass	QBS to current leadframe		
PTC	A5	JESD22-A105	Power Temperature Cycling: -40°C/+125°C/1000 cycles	1	45	45	Pass	N/A		
HTSL	A6	JESD22-A103	High Temperature Storage Life: 150°C/1000 hours or 175°C/500 hours	1	45	45	Pass	QBS to current leadframe		
			TEST GROUP B – ACCELERATED LIFE	TIME SIMU	LATION TE	ESTS (3)				
HTOL	B1	JESD22-A108	High Temp Operating Life: 125°C/1000 hours 150°C/408 hours	3	77	231	Pass	QBS to current leadframe		
ELFR	B2	AEC-Q100-008	Early Life Failure Rate:	3	800	2400	Pass	QBS to current leadframe		
			TEST GROUP C – PACKAGE ASSEN	IBLY INTEG	RITY TEST	S (3)				
WBS	C1	AEC-Q100-001	Wire Bond Shear Test: (Cpk > 1.67)	30 bonds	5 parts min.	30 bonds	Pass			
WBP	C2	Mil-Std-883 Method 2011	Wire Bond Pull: Each bonder used (Cpk > 1.67)	30 bonds	5 parts min.	30 bonds	Pass			
SD	C3	JESD22-B102	Solderability: (>95% coverage) 8 hr steam age (1 hour for Au-plated leads)	1	15	15		N/A		
PD	C4	JESD22-B100 JESD22-B108	Physical Dimensions: (Cpk > 1.67)	1	10	10	Pass			
SBS	C5	AEC-Q100-010	Solder Ball Shear: (Cpk > 1.67)	5 balls	10 parts min.	50	Pass			
LI	C6	JESD22-B105	Lead Integrity:	10 leads	5 parts min.	50		N/A		

TEST GROUP E- ELECTRICAL VERIFICATION									
TEST	E1	User/Supplier Specification	Pre and Post Stress Electrical Test:	All	All	All			
HBM	E2	AEC-Q100-002	Electrostatic Discharge, Human Body Model: (2kV - H2 or better)	1				N/A	
MM	E2	AEC-Q100-003	Electrostatic Discharge, Machine Model: (200V – M3 or better)	1				N/A	
CDM	E3	AEC-Q100-101	Electrostatic Discharge, Charged Device Model: (750V corner leads, 500V for all other pins)	1				N/A	
LU	E4	AEC-Q100-004	Latch-Up:	1	6	6		N/A	
ED	E5	AEC-Q100-009	Electrical Distributions: (Cpk > 1.67)	1	30	30	1/30/0		

(1) Grade 0 (or A): -40°C to +150°C ambient operating temperature range

Grade 1 (or Q): -40°C to +125°C ambient operating temperature range

Grade 2 (or T): -40°C to +105°C ambient operating temperature range

Grade 3 (or I): -40°C to +85°C ambient operating temperature range

Grade 4 (or C): -0°C to +150°C ambient operating temperature range

(2) These are recommended minimum lot/sample sizes. Lot/sample size may be reduced depending on available data.

(3) Generic data may be used.

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Reliability data shows characteristic failure mechanisms of the specific environmental stress as documented in the industry standards for each stress condition.

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